

30V PNP MEDIUM POWER TRANSISTOR IN SOT223

Features

- BV_{CEO} > -30V
- I_C = -1A High Continuous Current
- Excellent h_{FE} Characteristics up to -2A
- Low Saturation Voltage V_{CE(sat)} < -0.5V @ -1A
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

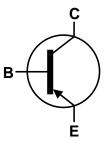
Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound;
 UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208(©3)
- Weight: 0.112 grams (Approximate)

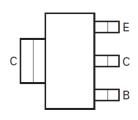
SOT223



Top View



Device Symbol



Top View Pin-Out

Ordering Information (Note 4)

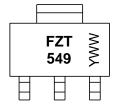
Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FZT549TA	AEC-Q101	FZT549	7	12	1,000

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http"//www.diodes.com/products/packages.html.

Marking Information

SOT223



FZT 549 = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 5= 2015) WW or $\overline{W}W$ = Week Code (01~53)



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-35	V
Collector-Emitter Voltage	$V_{\sf CEO}$	-30	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current	Ic	-1	Α
Peak Pulse Current	I _{CM}	-2	Α

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 5)	р	2	W
Power Dissipation	(Note 6)	P _D	3	W
Thermal Resistance, Junction to Ambient	(Note 5)	D	62.5	°C/W
Thermal Resistance, Junction to Ambient	(Note 6)	R _{0JA}	41.7	°C/W
Thermal Resistance, Junction to Leads (Note 7	$R_{ heta JL}$	19.4	°C/W	
Operating and Storage Temperature Range	$T_{J_1}T_{STG}$	-55 to +150	°C	

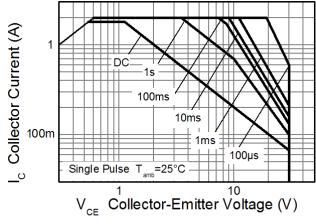
ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

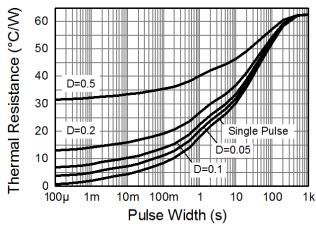
- 5. For a device mounted with the collector lead on 25mm x 25mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
 6. Same as Note 5, except the device is mounted on 50mm x 50mm single sided 2oz weight copper.
 7. Thermal resistance from junction to solder-point (at the end of the collector lead).
 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



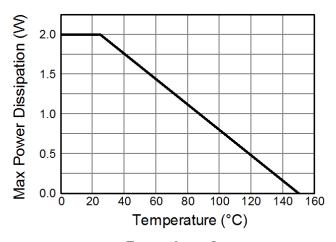
Thermal Characteristics and Derating Information



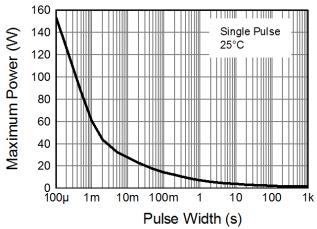
Safe Operating Area



Transient Thermal Impedance

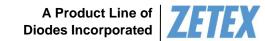


Derating Curve



Pulse Power Dissipation





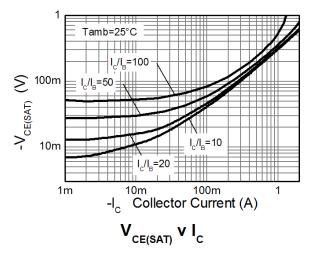
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

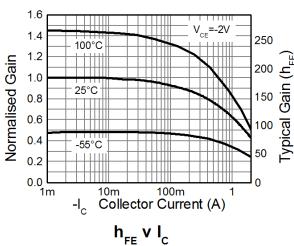
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-35	_	_	V	$I_{C} = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	-30	_	_	V	$I_C = -10mA$
Emitter-Base Breakdown Voltage	BV_{EBO}	-7	_	_	V	$I_E = -100 \mu A$
Collector Cut-Off Current	Ісво	-	-	-100 -10	nA uA	$V_{CB} = -30V$ $V_{CB} = -30V$, $T_{amb} = +100$ °C
Collector Cut-Off Current	I _{CES}	_	_	-100	nA	V _{CES} = -30V
Emitter Cut-Off Current	I _{EBO}	_	_	-100	nA	V _{EB} = -4V
Collector-Emitter Saturation Voltage (Note 9)	V _{CE(sat)}	<u> </u>	_ _	-0.50 -0.75	V	I _C = -1A, I _B = -100mA I _C = -2A, I _B = -200mA
Base-Emitter Saturation Voltage (Note 9)	$V_{BE(sat)}$	_	_	-1.25	V	$I_C = -1A$, $I_B = -100mA$
Base-Emitter Turn-On Voltage (Note 9)	V _{BE(on)}	_	_	-1.0	V	$I_C = -1A$, $V_{CE} = -2V$
DC Current Transfer Static Ratio (Note 9)	h _{FE}	70 100 80 30	- - -	300 - -	-	$\begin{split} I_{C} &= -50 \text{mA}, \ V_{CE} = -2 \text{V} \\ I_{C} &= -500 \text{mA}, \ V_{CE} = -2 \text{V} \\ I_{C} &= -1 \text{A}, \ V_{CE} = -2 \text{V} \\ I_{C} &= -2 \text{A}, \ V_{CE} = -2 \text{V} \end{split}$
Transitional Frequency (Note 9)	f⊤	100	-	-	MHz	$V_{CE} = -5V$, $I_{C} = -100$ mA f = 100MHz
Output Capacitance (Note 9)	C_{obo}	_	_	10	pF	V _{CB} = -10V. f = 1MHz
Switching Times	t _{on} t _{off}		50 300	_	ns	$I_{C} = -500 \text{mA}, V_{CC} = -10 \text{V}$ $I_{B1} = I_{B2} = -50 \text{mA}$

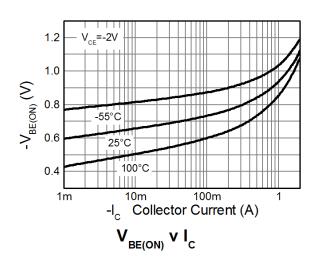
Note: 9. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.

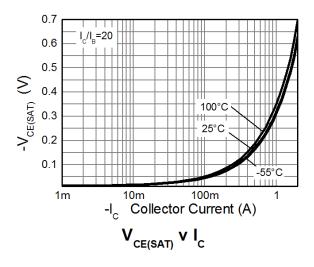


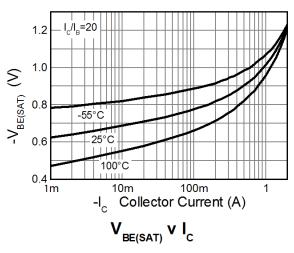
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)







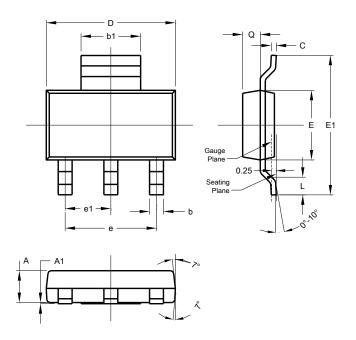






Package Outline Dimensions

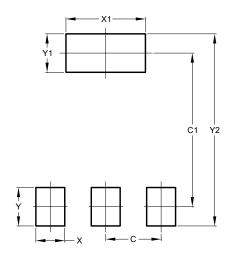
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b	0.60	0.80	0.70		
b1	2.90	3.10	3.00		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
Е	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	_	_	4.60		
e1	_	_	2.30		
L	0.85	1.05	0.95		
Q	0.84	0.94	0.89		
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Υ	1.60
Y1	1.60
Y2	8.00





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